# 2SK3948G

## Silicon N-channel junction FET

For impedance conversion in low frequency For electret capacitor microphone

### ■ Features

- Low noise voltage NV
- High voltage gain GV
- Thin package: TSSSMini3-F2 (1.2 mm × 1.2 mm × 0.33 mm)

## ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Drain-source voltage (Gate open)	$V_{\rm DSO}$	20	V	
Drain-gate voltage (Souece open)	$V_{DGO}$	20	V	
Drain-source current (Gate open)	$I_{DSO}$	2	mA	
Drain-gate current (Souece open)	$I_{DGO}$	2	mA	
Power dissipation	P <sub>D</sub>	100	mW	
Operating ambient temperature	T <sub>opr</sub>	-20 to +80	°C	
Storage temperature	T <sub>stg</sub>	-55 to +125	°C	

#### ■ Package

- Code
  - TSSSMini3-F2
- Pin Name
  - 1: Drain
  - 2: Source
  - 3: Gate
- Marking Symbol: 4X

### ■ Electrical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain current *1	$I_{\mathrm{D}}$	$V_{DD} = 2.0 \text{ V}, R_d = 2.2 \text{ k}\Omega \pm 1\%$	170		470	μΑ
Drain-source current *2	I <sub>DSS</sub>	$V_{DD} = 2.0 \text{ V}, R_d = 2.2 \text{ k}\Omega \pm 1\%, V_{GS} = 0$	180	60.	450	μΑ
Mutual conductance	g <sub>m</sub>	$V_{DS} = 2.0 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$	660	1500		μS
Noise voltage *3	NV	$V_{DD} = 2.0 \text{ V}, R_d = 2.2 \text{ k}\Omega \pm 1\%$ $C_O = 5 \text{ pF}, A\text{-curve}$	ST ST.		8	μV
	$G_{V1}$	$V_{DD} = 2.0 \text{ V}, R_d = 2.2 \text{ k}\Omega \pm 1\%$ $C_O = 5 \text{ pF}, e_G = 10 \text{ mV}, f = 1 \text{ kHz}$	-5.0	-1.0		
Voltage gain $G_{V2} \\$ $G_{V3}$	G <sub>V2</sub>	$V_{DD} = 12 \text{ V}, R_d = 2.2 \text{ k}\Omega \pm 1\%$ $C_O = 5 \text{ pF}, e_G = 10 \text{ mV}, f = 1 \text{ kHz}$	-3.0	3.0		
	G <sub>V3</sub>	$V_{DD} = 1.5 \text{ V}, R_d = 2.2 \text{ k}\Omega \pm 1\%$ $C_O = 5 \text{ pF}, e_G = 10 \text{ mV}, f = 1 \text{ kHz}$	-7.0	-1.5		dB
Voltage gain difference	$\Delta  G_{V}.f ^{*4}$	$V_{DD} = 2.0 \text{ V}, R_d = 2.2 \text{ k}\Omega \pm 1\%$ $C_O = 5 \text{ pF}, e_G = 10 \text{ mV}$ f = 1  kHz to  70  Hz		0.0	1.7	
	$ G_{V1}-G_{V3} $			0.5	1.0	dB

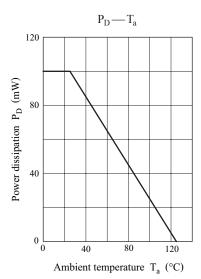
- $Note) \ 1. \ Measuring \ methods \ are \ based \ on \ JAPANESE \ INDUSTRIAL \ STANDARD \ JIS \ C \ 7030 \ measuring \ methods \ for \ transistors.$ 
  - 2. A protection diode is built-in between gate and source of transistor. However if forward current flows between gate and source transistor might be damaged. So please be careful not insert reverse.
  - 3. \*1:  $I_D$  is assured for  $I_{DSS}$ .
    - \*2: Rank classification

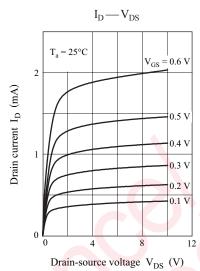
Rank	Т	U
$I_{D}(\mu A)$	170 to 330	270 to 470
$I_{DSS}(\mu A)$	180 to 320	280 to 450

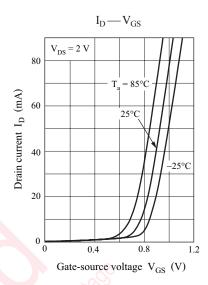
- \*3: NV is assured for design.
- \*4:  $\Delta |G_V|$  . f | is assured for AQL 0.065. (The measurement method is used by source-grounded circuit.)

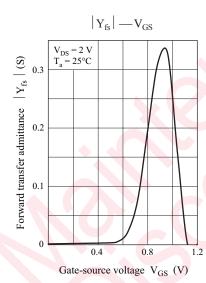
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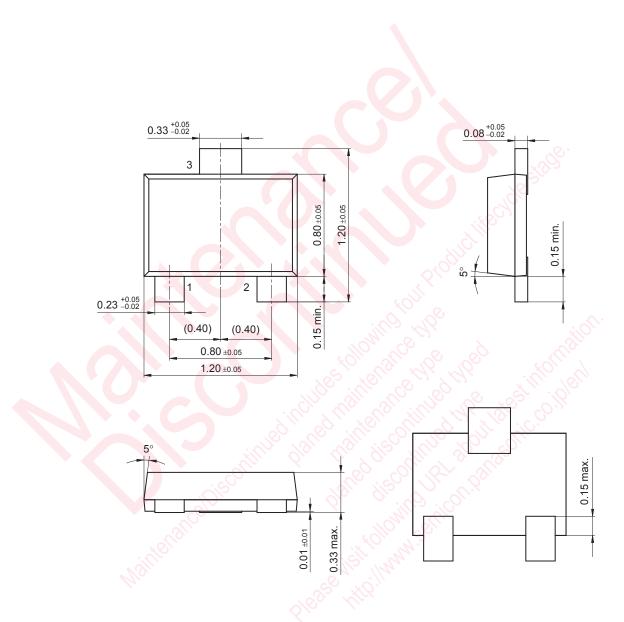




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TSSSMini3-F2

Unit: mm



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